

Potential V due to a spherical shell

Electric field due to a spherical shell $\vec{E} = \frac{Q}{4\pi\epsilon_0 r^2} \hat{r}$ outside, $E = 0$ inside

Potential V outside

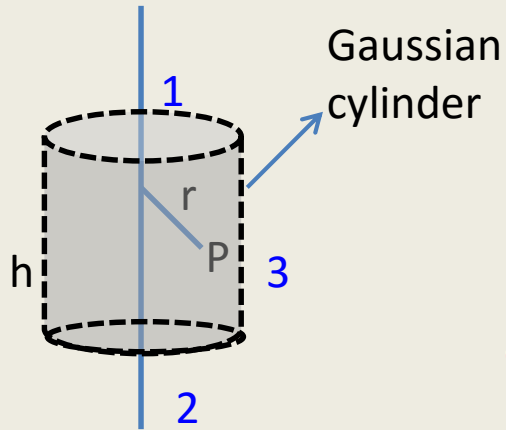
$$V(r) = - \int_{\infty}^r E \cdot dr = \frac{\sigma R^2}{\epsilon_0 r} = \frac{Q}{4\pi\epsilon_0 r} \quad \text{Total charge is centered at the origin}$$

Potential V inside (depends on what the electric field outside is!)

$$V(r) = - \int_{\infty}^R E_{\text{out}} \cdot dr - \int_R^r E_{\text{in}} \cdot dr = \frac{\sigma R^2}{\epsilon_0 R} = \frac{Q}{4\pi\epsilon_0 R} \quad \text{Potential is constant inside}$$

Potential V due to an infinite wire (λ), cylinder (ρ)

(A). Electric field at P at a distance r from the wire

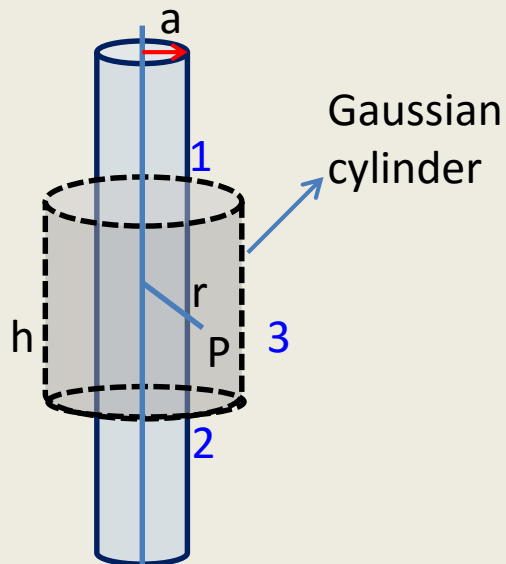


Draw Gaussian surface (cylinder of radius r and height h , enclosing the wire) such that the P is on the surface.

From symmetry, $\vec{E} = E\hat{r} \Rightarrow$ flux through flat surfaces (1 & 2) = 0, $E \perp dS$

$$\oiint \vec{E} \cdot d\vec{s} = E 2\pi r h = \frac{\lambda h}{\epsilon_0} \Rightarrow \vec{E} = \pm \hat{r} \frac{\sigma}{2\pi\epsilon_0 r}$$

(B). E due to infinite cylinder, volume charge density ρ



(i) E outside

$$\oiint \vec{E} \cdot d\vec{s} = E 2\pi r h = \frac{\rho \pi a^2 h}{\epsilon_0} \Rightarrow \vec{E}_{\text{out}} = \hat{r} \frac{\rho a^2}{2\epsilon_0 r}$$

(ii) E inside

$$\oiint \vec{E} \cdot d\vec{s} = E 2\pi r h = \frac{\rho \pi r^2 h}{\epsilon_0} \Rightarrow \vec{E}_{\text{in}} = \hat{r} \frac{\rho r}{2\epsilon_0}$$

Potential V due to an infinite wire λ

$$\vec{E}(r) = \frac{\lambda}{2\pi\epsilon_0 r} \hat{r}$$

$$V(r) = - \int_{\infty}^r E \cdot dr = - \frac{\lambda}{2\pi\epsilon_0} \ln r \Big|_{\infty}^r$$

**Infinity as a reference point is NOT good;
only a potential difference can be found in this case**

$$V(r) = - \frac{\lambda}{2\pi\epsilon_0} \ln \frac{r}{a} \quad \text{where } r = a \text{ is a point where the potential is well defined}$$

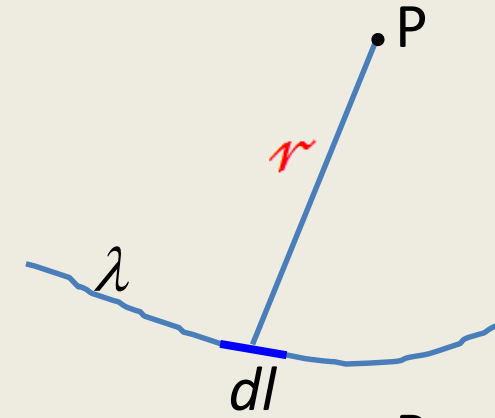
with the condition that

$$\vec{E} = -\vec{\nabla}V = \frac{\lambda}{2\pi\epsilon_0} \frac{\partial}{\partial r} \left(\ln \frac{r}{a} \right) \hat{r} = \frac{\lambda}{2\pi\epsilon_0 r} \hat{r}$$

Potential due to CONTINUOUS CHARGE DISTRIBUTIONS

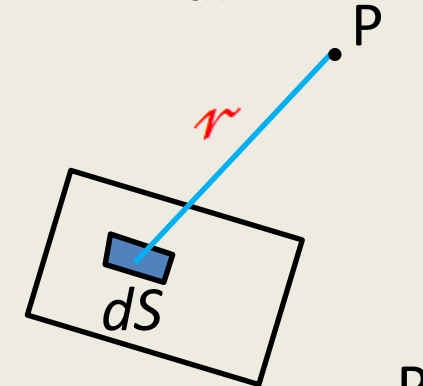
LINE CHARGE

$$V(P) = \frac{1}{4\pi\epsilon_0} \int \frac{\lambda dl}{r}$$



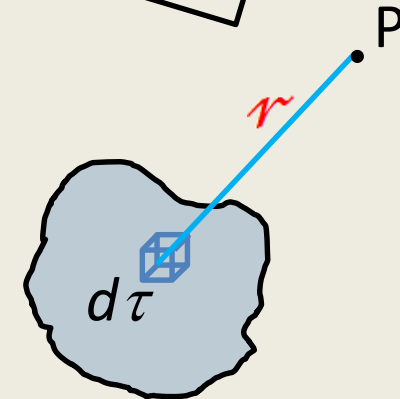
SURFACE CHARGE

$$V(P) = \frac{1}{4\pi\epsilon_0} \int \frac{\sigma dS}{r}$$

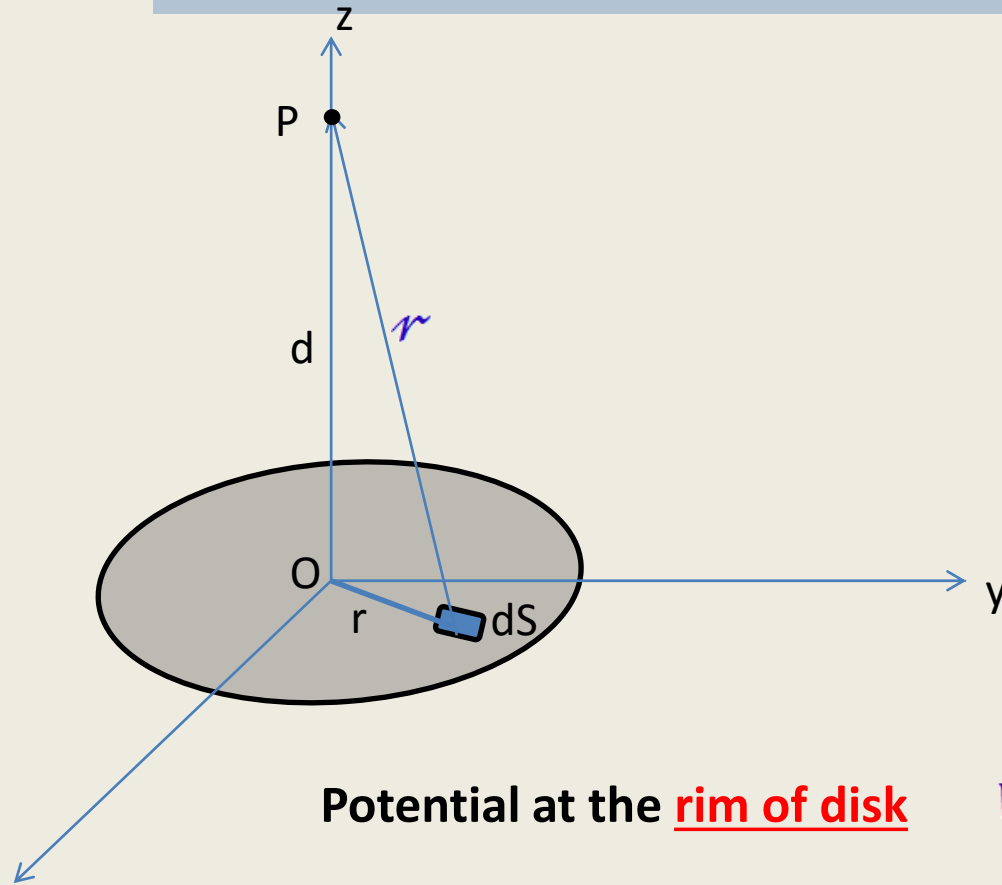


VOLUME CHARGE

$$V(P) = \frac{1}{4\pi\epsilon_0} \int \frac{\rho d\tau}{r}$$



Potential due to uniformly charged disk (σ), radius a , along the axis



$$\begin{aligned} V(P) &= \frac{1}{4\pi\epsilon_0} \int \frac{\sigma dS}{r} \\ &= \frac{\sigma}{4\pi\epsilon_0} \iint \frac{r dr d\phi}{\sqrt{(r^2 + d^2)}} \\ &= \frac{\sigma}{2\epsilon_0} \left\{ \sqrt{a^2 + d^2} - d \right\} \end{aligned}$$

Potential at the centre of disk, $d = 0$

$$V(O) = \frac{\sigma a}{2\epsilon_0} = \text{constant}$$

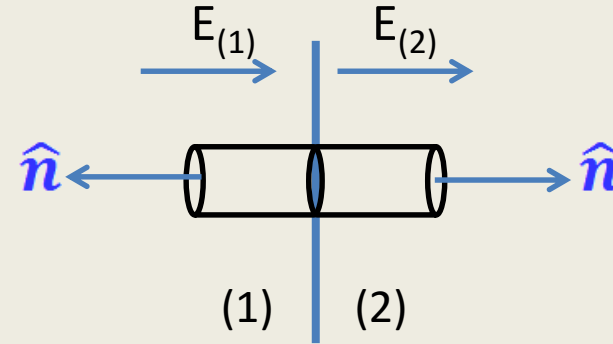
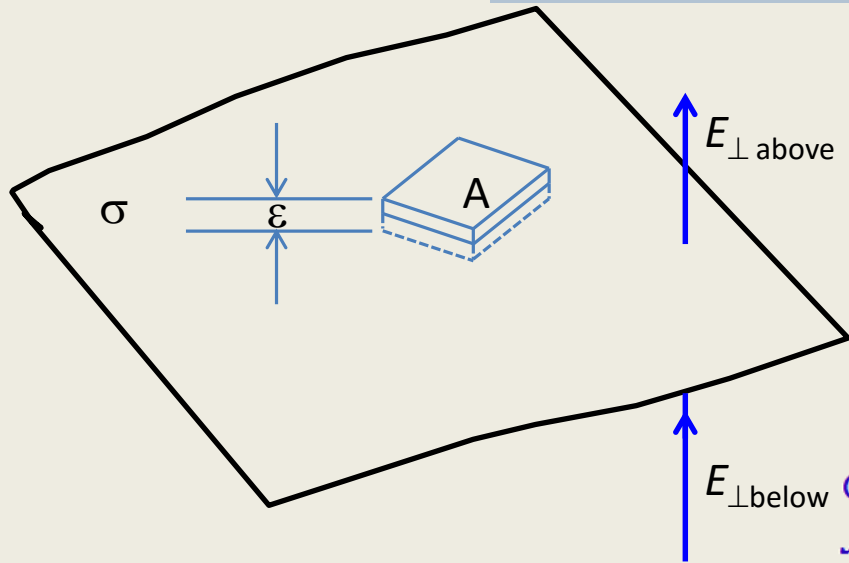
$$V = \frac{\sigma a}{\pi\epsilon_0} \quad \text{Check This!! (Hint: Use a suitable co-ordinate system)}$$

Potential at the rim of disk

Potential is max. at the centre of disk and decreases towards the rim! **DISK is NOT an EQUIPotential surface**

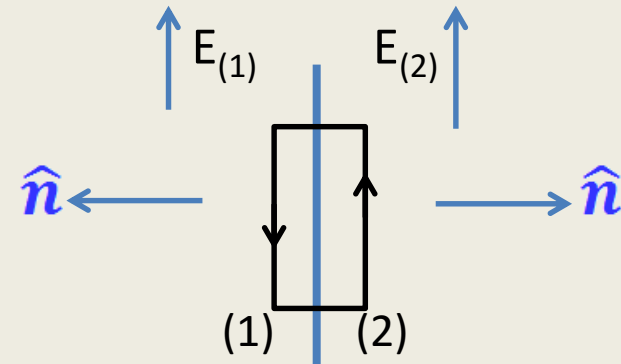
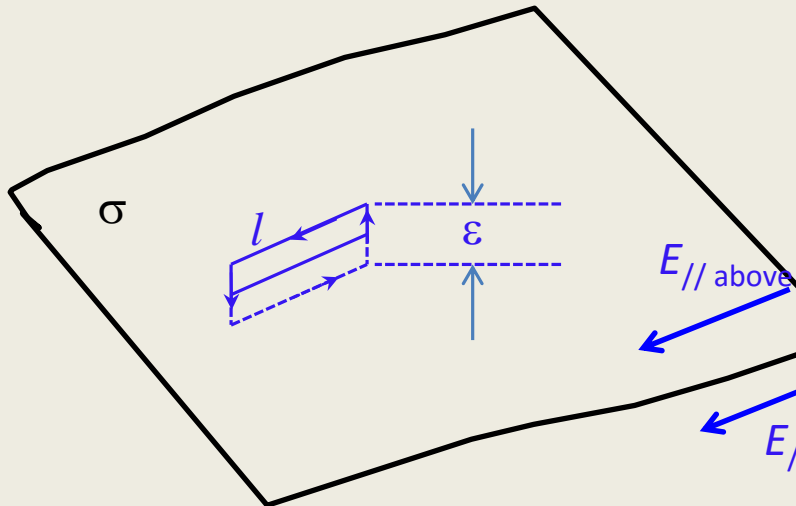
If $d \gg a$
$$V = \frac{\sigma a^2}{4\epsilon_0 d} = \frac{Q}{4\pi\epsilon_0 d} = \text{potential due to pt.charge}$$

Electrostatic boundary conditions



$$\oiint \vec{E} \cdot d\vec{s} = (E_{2\perp} - E_{1\perp})A = \frac{Q}{\epsilon_0} = \frac{\sigma A}{\epsilon_0}$$

NORMAL component of E is discontinuous by an amount σ/ϵ_0 across a surface charge



$$\oint \vec{E} \cdot d\vec{l} = 0 \Rightarrow (E_{2\parallel} - E_{1\parallel})L = 0 \Rightarrow E_{2\parallel} = E_{1\parallel}$$

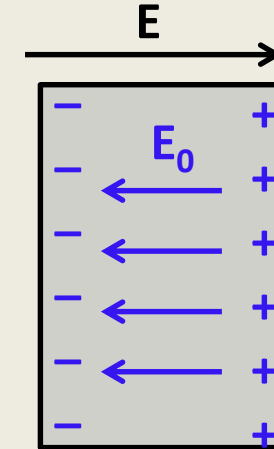
PARALLEL component of E is continuous

CONDUCTORS

Electrical conductor : large number of free e^- s; $10^{28}/m^3$; but uncharged

What happens when a conductor is placed in an electric field

- e^- s move to one side
- Only e^- s are mobile; +ve ions are left at other end
- Charges pile up; +ve on one side, -ve on other side
- Movements of charges occur till $E_0 = E$
- E_0 exactly cancels the field inside the conductor



Properties of conductors

- (i) $E = 0$ inside (material) of a conductor
- (ii) $V = \text{const}$ in the volume of the conductor : EQUIPOTENTIAL surface

$$\vec{E} = -\vec{\nabla}V = 0 \Rightarrow V = \text{const}$$

$$-\int_a^b \vec{E} \cdot d\vec{l} = V(a) - V(b) = 0 \Rightarrow V(a) = V(b)$$

- (iii) Charge density $\rho = 0$ inside a conductor $\nabla \cdot E = \frac{\rho}{\epsilon_0} = 0 \Rightarrow \rho = 0$

No net charge; NO free charges can reside inside volume of a metal

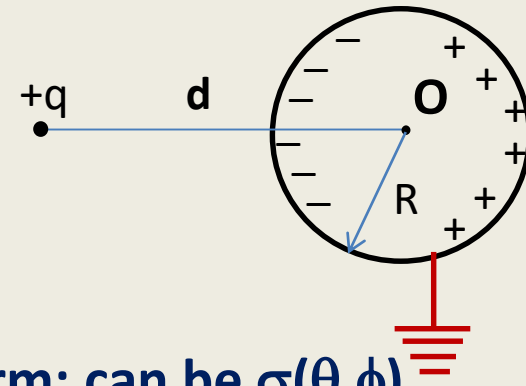
- (iv) Any added charge can reside only on the surface : **only surface charge density**

- (v) E should be \perp surface just outside : any tangential component will make the charges flow.

$$\vec{E} = \frac{\sigma}{\epsilon_0} \hat{n}$$

Point charge near a conductor

- conductor will move charges around such that $E = 0$ inside
- Since $-ve$ charges are closer to $+q$, net attraction
- Charge density on the conductor will be non-uniform; can be $\sigma(\theta, \phi)$



Potential on the conductor

$$\begin{aligned}
 V(O) &= \frac{q}{4\pi\epsilon_0 d} + \iint \frac{\sigma(\theta, \phi)}{4\pi\epsilon_0 R} dS = \frac{q}{4\pi\epsilon_0 d} + \frac{1}{4\pi\epsilon_0 R} \iint \sigma(\theta, \phi) dS \\
 &= \frac{q}{4\pi\epsilon_0 d}
 \end{aligned}$$

Earthing (grounding) the conductor

Cavity inside a conductor

(A) Charge outside the conductor:

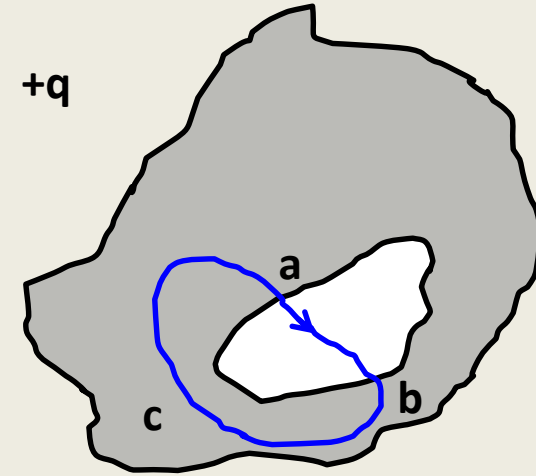
- Since $E = 0$ inside the conductor, E is cancelled at the outer surface
- $E = 0$ inside the conductor ; inside the cavity
- For electrostatic field, $\oint \vec{E} \cdot d\vec{l} = 0$

$$\oint \vec{E} \cdot d\vec{l} = \int_{a \rightarrow b} \vec{E} \cdot d\vec{l} + \int_{b \rightarrow c \rightarrow a} \vec{E} \cdot d\vec{l} = 0$$

$$\int_{b \rightarrow c \rightarrow a} \vec{E} \cdot d\vec{l} = 0 \text{ since } E = 0 \text{ inside conductor}$$

$$\text{Hence to make } \int_{a \rightarrow b} \vec{E} \cdot d\vec{l} = 0, \quad \vec{E} \text{ has to be zero}$$

- cavity and contents are electrically shielded from outside electric field



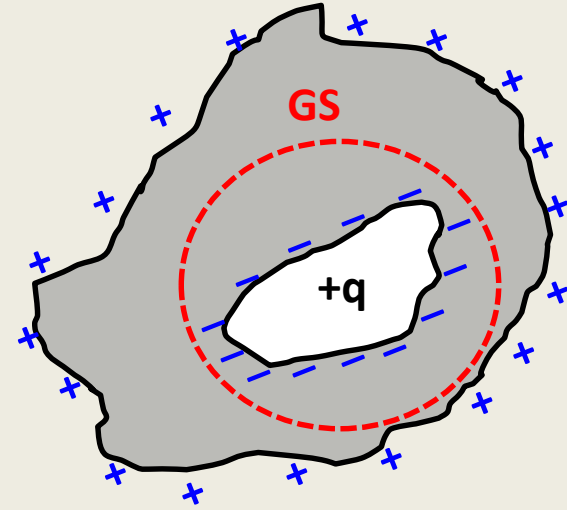
$$V(r_b) - V(r_a) = - \int_{r_a}^{r_b} \vec{E} \cdot d\vec{l}$$

Since $V(r_b) = V(r_a)$ for a conductor
(equipotential surface)

$$\int_{a \rightarrow b} \vec{E} \cdot d\vec{l} = 0$$

(B) Charge INSIDE cavity:

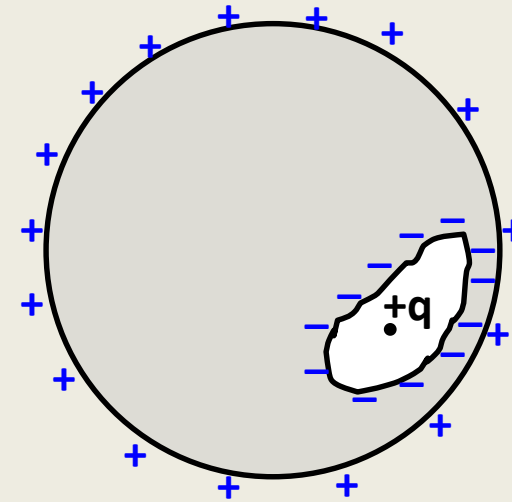
- $E \neq 0$ Inside the cavity!
- $E = 0$ inside the conductor; E is cancelled at the cavity walls
- Conductor will move charges around such that $E = 0$ inside
- $-q$ will be induced on the Cavity wall
- $+q$ will be distributed at the outer surface



Cavity inside a spherical conductor

- +q inside cavity
- −q induced on the cavity wall
- +q induced on the outer surface : **uniform**
- +q inside cavity and −q induced completely kills off the electric field inside the metal

$$E_{\text{out}} = \frac{q}{4\pi\epsilon_0 r^2}; \quad V_{\text{out}} = \frac{q}{4\pi\epsilon_0 r}$$



Spherical shell (conductor) with charge +q at the centre

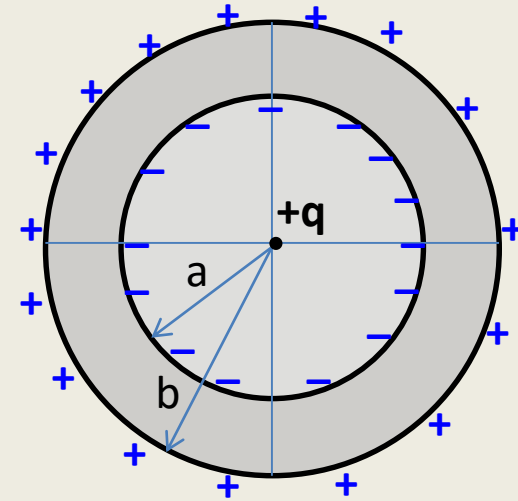
Surface charge density

$$\sigma_a = \frac{-q}{4\pi a^2} \quad \sigma_b = \frac{+q}{4\pi b^2}$$

$$\vec{E}_{r < a} = \frac{q}{4\pi\epsilon_0 r^2} \hat{r}$$

$$\vec{E}_{a < r < b} = 0$$

$$\vec{E}_{r > b} = \frac{q}{4\pi\epsilon_0 r^2} \hat{r}$$



$$V_{r > b} = \frac{q}{4\pi\epsilon_0 r}$$

$$V_{a < r < b} = \frac{q}{4\pi\epsilon_0 b} = \text{const}$$

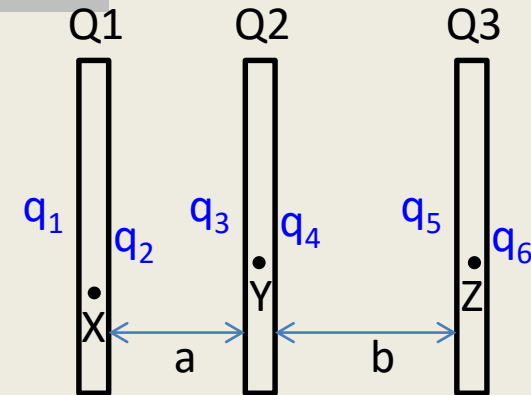
$$V_{r < a} = \frac{q}{4\pi\epsilon_0} \left(\frac{1}{b} + \frac{1}{r} - \frac{1}{a} \right)$$

Parallel plate CONDUCUTORS

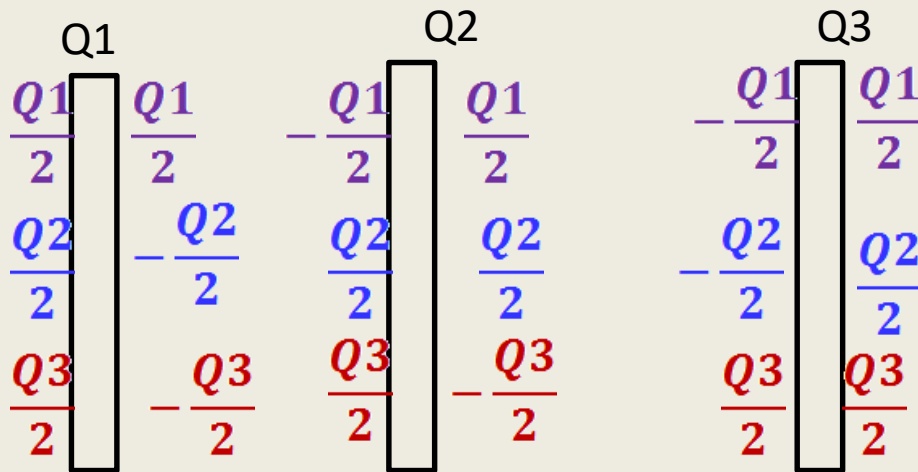
$$E(X) = \frac{1}{A\epsilon_0}(q_1 - q_2 - q_3 - q_4 - q_5 - q_6) = 0$$

$$(q_1 - [Q1 - q_1] - q_3 - [Q2 - q_3] - q_5 - [Q3 - q_5]) = 0$$

$$q_1 = \frac{1}{2}(Q1 + Q2 + Q3) \quad q_2 = \frac{1}{2}(Q1 - Q2 - Q3)$$



Similarly, for $E(Y)$, we can get q_3 and q_4 & $E(Z)$, we can get q_5 and q_6



- Outermost surfaces divide the whole charge equally among them
- Inner surfaces carry equal and opposite charges and cancel each other

Force on the surface charge of a CONDUCTOR

Consider the patch as a charge sheet

$$E_{\text{patch}} = + \frac{\sigma}{2\epsilon_0} \text{ right} \quad E_{\text{patch}} = - \frac{\sigma}{2\epsilon_0} \text{ left}$$

Then how do we get the asymmetric electric field of a conducting surface? i.e., zero immediately inside and non-zero immediately outside ?

We have to add an extra e.f. (which is not generated locally by the patch). The required field is

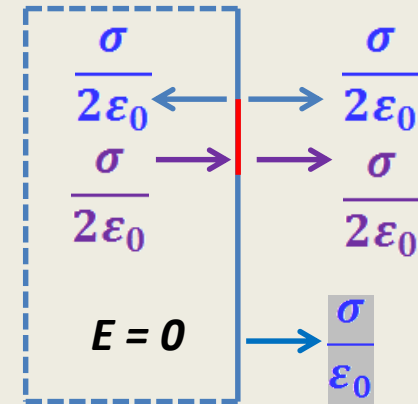
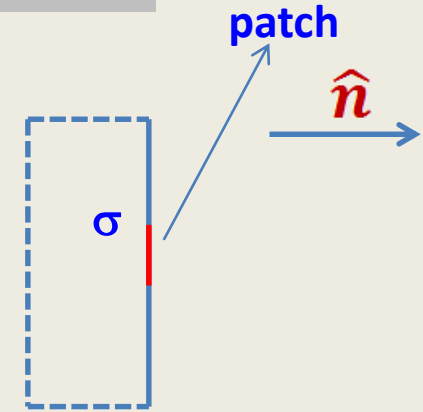
$$E' = \frac{\sigma}{2\epsilon_0} \text{ right and left}$$

Since the e.f. generated locally by the Patch cannot exert a force on itself, the force on the patch is due to E'

$$f = \frac{\sigma^2}{2\epsilon_0} \hat{n} \text{ acts outwards!}$$

Electrostatic pressure (**acting outwards**) on any charged conductor : $P = \frac{\epsilon_0}{2} E^2$

That is why a charged soap bubble bursts?



Force on the surface charge of a CONDUCTOR

Electric field just outside a conductor , $\vec{E} = \frac{\sigma}{\epsilon_0} \hat{n}$

Hence $\frac{\partial V}{\partial n} = -\frac{\sigma}{\epsilon_0}$ $\sigma = -\epsilon_0 \left. \frac{\partial V}{\partial n} \right|_{\text{surface}}$

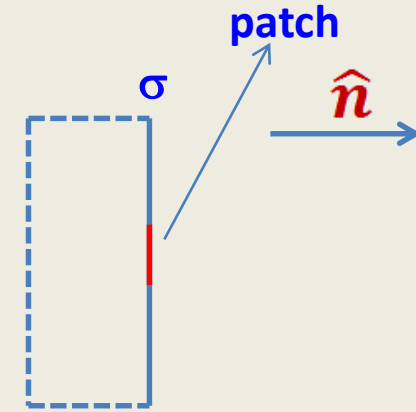
Force on the surface charge of a CONDUCTOR

When electric field is present, surface charge will experience a force, $F = QE$

Force per unit area $f = \sigma E$

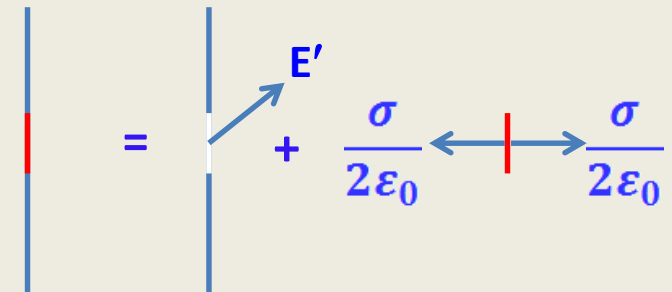
Let us calculate the force on a small patch

But E is discontinuous at the surface charge. ie, $E = 0$ inside the conductor and σ/ϵ_0 outside. So which field?



$E_{\text{tot}} = E_{\text{patch}} + E'$, where E' is field at the patch due to everything else

Patch cannot exert a force on itself. Hence the force on the patch is due to E'



$$\vec{E}_{\text{right}} = E' + \frac{\sigma}{2\epsilon_0} \hat{n} \quad \vec{E}_{\text{left}} = E' - \frac{\sigma}{2\epsilon_0} \hat{n}$$

$$\vec{E}' = \frac{1}{2} (\vec{E}_{\text{right}} + \vec{E}_{\text{left}}) = \vec{E}_{\text{average}} = \frac{\sigma}{2\epsilon_0} \hat{n} \quad f = \frac{\sigma^2}{2\epsilon_0} \hat{n} \text{ acts outwards!}$$

$$\text{Electrostatic pressure : } P = \frac{\epsilon_0}{2} E^2$$

Special techniques for calculating potentials

Uniqueness theorem for potential

$$V = \int \frac{1}{4\pi\epsilon_0 r} \sigma dS$$

For a conductor σ is complicated

$$\vec{\nabla} \cdot \vec{E} = \frac{\rho}{\epsilon_0}, \quad \vec{E} = -\vec{\nabla}V \quad \text{and hence} \quad \nabla^2 V = -\frac{\rho}{\epsilon_0} \quad \text{Poisson's Equation}$$

$$\nabla^2 V = 0 \quad \text{in a charge free region} \quad \text{Laplace's Equation}$$

$$\frac{\partial^2 V}{\partial x^2} + \frac{\partial^2 V}{\partial y^2} + \frac{\partial^2 V}{\partial z^2} = 0$$

$$\text{In 1-D, } \frac{d^2 V}{dx^2} = 0 \quad \Rightarrow \quad V = mx + c \quad \text{Boundary conditions (which?)}$$

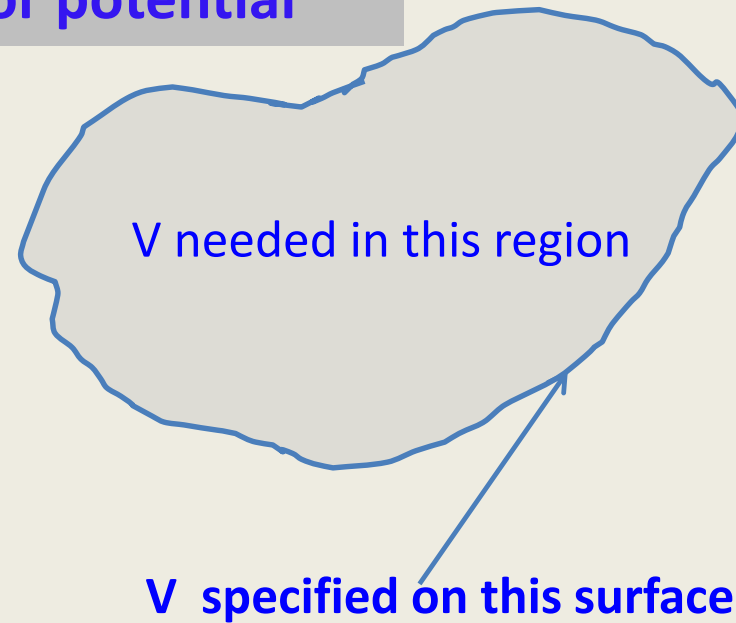
- $V(x)$ is the average of $V(x+R)$ and $V(x-R)$
 - Laplace's Equation implies no local maxima or minima; extreme values of V must occur at end points only

Uniqueness theorem for potential

Uniqueness theorem:

- (i) If a solution can be found (it does not matter which way) that satisfies Laplace's equation (OR Poisson's eqn)
- (ii) If it has the correct value on the boundary

Then the solution is **UNIQUE**



Let V_1 and V_2 are 2 solutions. Then $\nabla^2 V_1 = 0 = \nabla^2 V_2$

Let $V_3 = V_1 - V_2$ Then $\nabla^2 V_3 = \nabla^2 V_1 - \nabla^2 V_2 = 0$

Also, $V_3 = 0$ at the boundary, since $V_1 = V_2$ at the boundary. But Laplace's equation permits no local extrema, it can occur only at the boundaries.

Hence V_3 is zero everywhere.

(i) Cartesian coordinates

Laplace's Equation in Cartesian coordinates is given by (2-D)

$$\frac{\partial^2 V}{\partial x^2} + \frac{\partial^2 V}{\partial y^2} = 0$$

Look for solutions of the type $V(x, y) = X(x) Y(y)$

$$Y \frac{\partial^2 X}{\partial x^2} + X \frac{\partial^2 Y}{\partial y^2} = 0 \text{ divide by } V(x, y) \rightarrow \frac{1}{X} \frac{d^2 X}{dx^2} + \frac{1}{Y} \frac{d^2 Y}{dy^2} = 0$$

$$\frac{1}{X} \frac{d^2 X}{dx^2} = - \frac{1}{Y} \frac{d^2 Y}{dy^2}$$

$$\frac{d^2 X}{dx^2} = kX, \quad \frac{d^2 Y}{dy^2} = -kY$$

Take the constant as k^2

$$\frac{d^2X}{dx^2} - k^2X = 0, \quad \frac{d^2Y}{dy^2} + k^2Y = 0$$

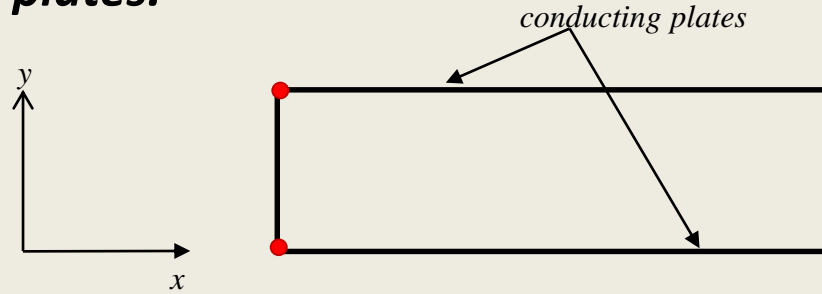
Solutions are

$$X(x) = Ae^{kx} + Be^{-kx}, \quad Y = C \sin(ky) + D \cos(ky)$$

$$V(x, y) = X(x) Y(y) = \{Ae^{kx} + Be^{-kx}\} \{C \sin(ky) + D \cos(ky)\}$$

where A, B, C, D are constants to be determined from the boundary conditions of the given problem.

Example : Consider two semi-infinite, grounded, **conducting plates** lying parallel to the x - z plane, one at $y = 0$, and the other at $y = \pi$, as shown in the figure. The left end, at $x = 0$, is closed off by an **infinite strip** insulated from the two plates, and maintained at a specified potential $V_0(y)$. We have to find the potential in the region between the plates.



Solution : V is z -independent; 2-D Laplace's solution

Boundary conditions are

$$(1). V(x, 0) = 0, \quad (2). V(x, \pi) = 0$$

$$(3). V(0, y) = V_0(y), \text{ for } 0 \leq y \leq \pi$$

$$(4). V(x, y) \rightarrow 0 \text{ as } x \rightarrow \infty$$

$$V(x, y) = \{Ae^{kx} + Be^{-kx}\}\{C \sin(ky) + D \cos(ky)\}$$

$$(1). V(x, 0) = 0, \quad (2). V(x, \pi) = 0$$

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$$V(x, y) = \{Ae^{kx} + Be^{-kx}\}\{C \sin(ky) + D \cos(ky)\}$$

$$(4) \Rightarrow A = 0$$

$$(1) \Rightarrow D = 0$$

$$(2) \Rightarrow \sin(k\pi) = 0 \Rightarrow k \text{ is an integer, say } n$$

$$V(x, y) = \{Be^{-nx}\}\{C \sin(ny)\}$$

General solution:

$$V(x, y) = \sum_{n=1}^{\infty} E_n e^{-nx} \sin(ny)$$

satisfies boundary conditions 1, 2 and 4

Apply boundary conditions 3

$$V(0, y) = V_0(y) = \sum_{n=1}^{\infty} E_n \sin(ny)$$

Fourier sine series

Now we have to choose E_n that fits an arbitrary function $V_0(y)$

Multiply both sides by $\sin(n'y)$ and integrate over y from 0 to π

$$\int_0^{\pi} V_0(y) \sin(n'y) dy = \sum_{n=1}^{\infty} E_n \int_0^{\pi} \sin(ny) \sin(n'y) dy$$

From the orthogonality property of sine functions,

$$\int_0^{\pi} \sin(ny) \sin(n'y) dy = \frac{\pi}{2} \delta_{nn'} \quad \begin{aligned} \delta_{nn'} &= 1 \text{ if } n = n' \\ &= 0 \text{ if } n \neq n' \end{aligned}$$

$$E_n = \frac{2}{\pi} \int_0^{\pi} V_0(y) \sin(ny) dy$$

Now we have to get functional form of $V_0(y)$

As application of the above formalism: Take $V_0(y)$ as a constant potential V_0

$$E_n = \frac{2}{\pi} V_0 \int_0^{\pi} \sin(ny) dy = \frac{2}{\pi} V_0 \frac{1}{n} \{1 - \cos(n\pi)\}$$

$$E_n = 0, \text{ if } n \text{ is even}$$

$$= \frac{4V_0}{n\pi}, \text{ if } n \text{ is odd}$$

General solution:

$$V(x, y) = \sum_{n=1}^{\infty} E_n e^{-nx} \sin(ny)$$

$$V(x, y) = \frac{4V_0}{\pi} \sum_{n=1,3,5\dots}^{\infty} \frac{e^{-nx} \sin(ny)}{n}$$